



## 2-Line Uni-directional ESD Protection Diode

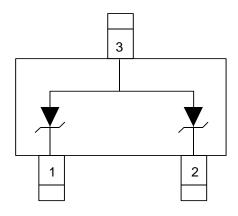
### **Description**

These dual monolithic silicon surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment. as computers, printers, business machines, communication systems, medical equipment and other applications. Their Uni-directional double ESD design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

#### **Features**

- Uni-directional ESD protection of two line
- Reverse stand-off voltage: 3.3V Max
- Low clamping voltage
- Low leakage current:nA level
- Response time is typically < 1ns
- Complies with following standards:
  - —IEC 61000-4-2 (ESD) immunity test
    - Air discharge: ±15kV
    - Contact discharge: ±8kV
  - —IEC61000-4-5 (Lightning) 11A (8/20µs)
- RoHS Compliant

### **Schematic and Pin Configuration**



Circuit and Pin Schematic

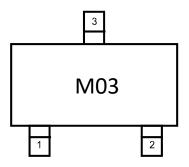
### **Mechanical Characteristics**

- Package: SOT-23
- Case Material: "Green" Molding Compound
- We declare that the material of product compliance with RoHS requirements and Halogen Free

#### **Applications**

- Computers
- Printers
- Communication systems
- Cellular Handsets and Accessories
- Portable Electronis
- Industrial Controls
- Set-Top Box

### Marking Information



M03 = Device Marking Code

### **Ordering Information**

Part Number	Shipping	Reel Size	
PSM03	3000/Tape &Reel	7 inch	



# Absolute Maximum Ratings (TA=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ррк	154	W
Peak Pulse Current (8/20µs)	IPP	11	A
ESD per IEC 61000-4-2 (Air)	N/	±15	kV
ESD per IEC 61000-4-2 (Contact)	Vesd	±8	kV
Lead temperature	T∟	260	Ĉ
Operating Temperature Range	T <sub>OP</sub>	-40 ~ +85	Ĉ
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	ĉ

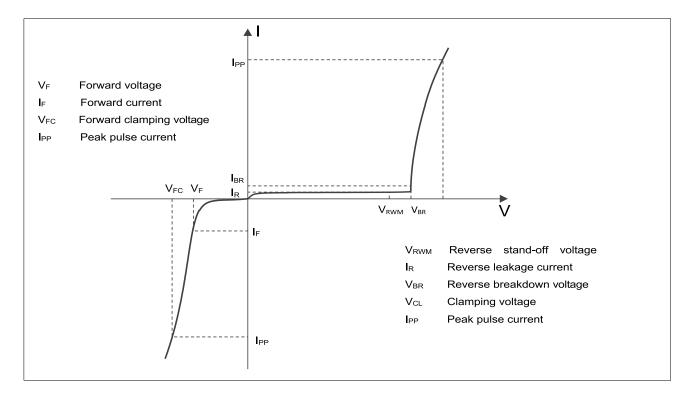
# Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	V <sub>RWM</sub>			3.3	V	
Reverse Breakdown Voltage	V <sub>BR</sub>	4.5			V	I <sub>T</sub> = 1mA
Reverse Leakage Current	IR			0.1	uA	V <sub>RWM</sub> =3.3 V
Clamping Voltage	Vc			7.0	V	I <sub>PP</sub> = 1A (8/20µs pulse)
Clamping Voltage	Vc			14	V	I <sub>PP</sub> = 11A (8/20µs pulse)
Junction Capacitance	6	0	70	100	- 5	$V_R = 0V$ , f = 1MHz (Pin1 or Pin2 to Pin3)
	CJ		35 50 pF	pF	$V_R = 0V$ , f = 1MHz (Pin1 to Pin2 or Pin2 to Pin1)	



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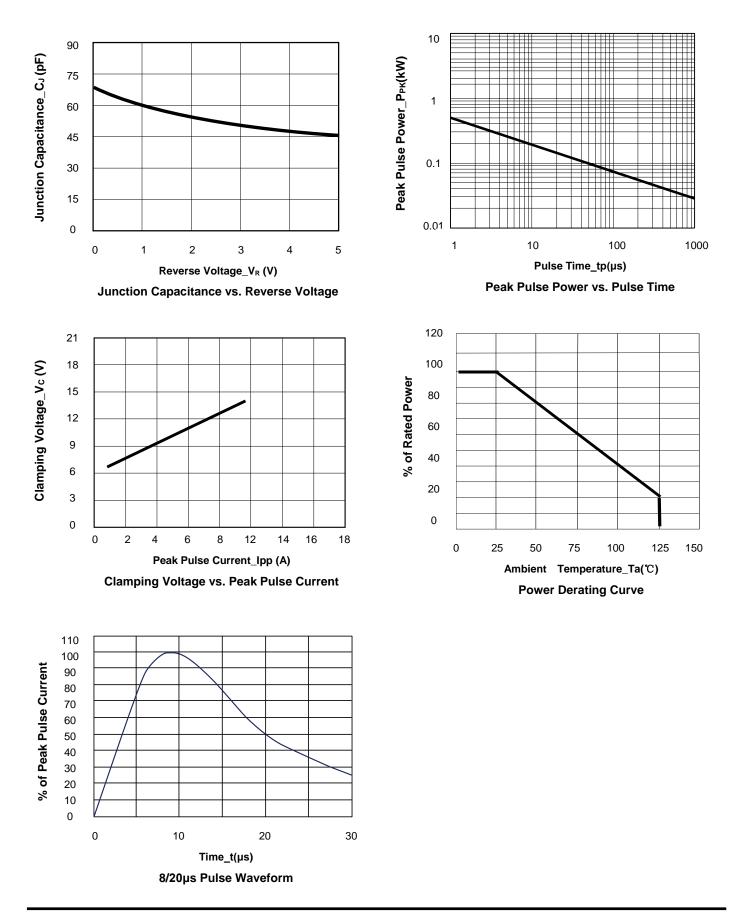
## <u>Electrical characteristics ( $T_A = 25 \degree$ , unless otherwise noted)</u>



Definitions of electrical characteristics



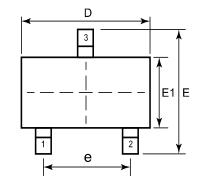
### Typical Performance Characteristics (TA=25°C unless otherwise Specified)

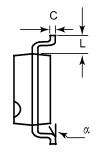


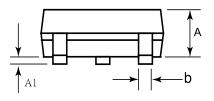


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# SOT-23 Package Outline Drawing

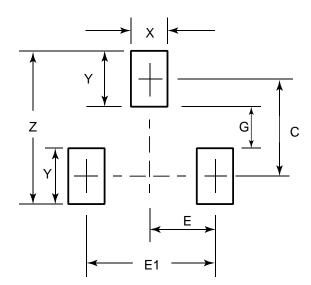






CVM	DIMENSIONS					
SYM	INCHES			MIL	LIMETE	RS
	MIN	NOM	MAX	MIN	NOM	МАХ
А	0.035	0.037	0.040	0.88	0.95	1.02
A1	0.000	-	0.004	0.01	-	0.10
b	0.012	-	0.020	0.30	-	0.51
С	0.003	-	0.007	0.08	-	0.18
D	0.110	0.114	0.120	2.80	2.90	3.04
E	0.082	0.093	0.104	2.10	2.37	2.64
E1	0.047	0.051	0.055	1.20	1.30	1.40
е	0.075 BSC			1.90 BSC		
L	0.022 BSC			(	).55 BSC	;
α	0°		8°	0°		8°

# **Suggested Land Pattern**

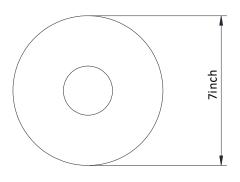


SYM	DIMENSIONS				
3111	MILLIMETERS	INCHES			
С	2.20	0.087			
E	0.95	0.037			
E1	1.90	0.075			
G	0.80	0.031			
х	1.00	0.039			
Y	1.40	0.055			
Z	3.60	0.141			

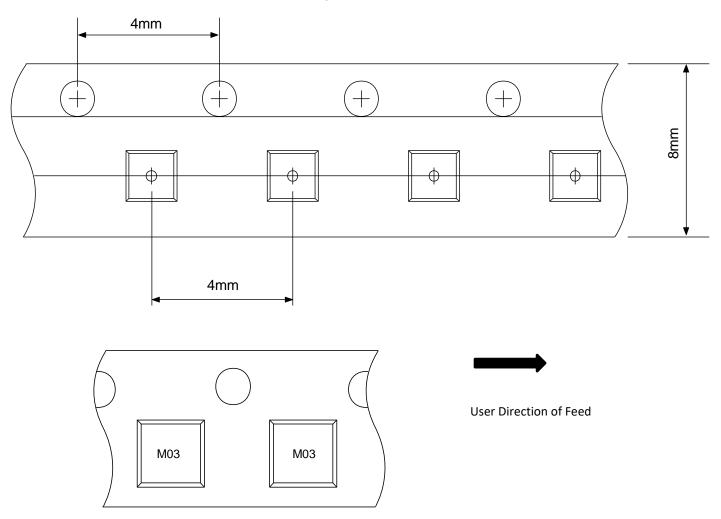


## TAPE AND REEL INFORMATION

#### **Reel Dimensions**



**Tape Dimensions** 





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